

Vishay High Power Products

Power Silicon Rectifier Diodes, 35 A/40 A/60 A

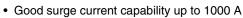


DO-203AB (DO-5)

35 A/40 A/60 A

DESCRIPTION/FEATURES

· Low leakage current series



- Can be supplied to meet stringent military, aerospace and other high reliability requirements
- Compliant to RoHS directive 2002/95/EC

MAJOR RAT	INGS AND CHARA	CTERISTICS	5				
PARAMETER	TEST CONDITIONS	1N1183	1N3765	1N1183A	1N2128A	UNITS	
		<mark>35</mark> ⁽¹⁾	35 (1)	40 (1)	60 ⁽¹⁾	А	
F(AV)	Tc	140 (1)	140 (1)	150 ⁽¹⁾	140 ⁽¹⁾	°C	
	50 Hz	480	380	765	860		
FSM	60 Hz	500 ⁽¹⁾	400 (1)	800 (1)	900 (1)	A	
l ² t	50 Hz	1140	730	2900	3700	A ² s	
1-1	60 Hz	1040	670	2650	3400	A-5	
l²√t		16 100	10 300	41 000	52 500	A²√s	
V _{RRM}	Range	50 to 600 ⁽¹⁾	700 to 1000 ⁽¹⁾	50 to 600 ⁽¹⁾	50 to 600 ⁽¹⁾	V	

Note

(1) JEDEC registered values

PRODUCT SUMMARY

I_{F(AV)}

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER		V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE (T _J = - 65 °C TO 200 °C ⁽²⁾) V	V _{RM} , MAXIMUM DIRECT REVERSE VOLTAGE (T _J = - 65 °C TO 200 °C ⁽²⁾) V		
1N1183	1N1183A	1N2128A	50 (1)	50 (1)	
1N1184	1N1184A	1N2129A	100 (1)	100 (1)	
1N1185	1N1185A	1N2130A	150 ⁽¹⁾	150 ⁽¹⁾	
1N1186	1N1186A	1N2131A	200 (1)	200 (1)	
1N1187	1N1187A	1N2133A	300 (1)	300 (1)	
1N1188	1N1188A	1N2135A	400 (1)	400 (1)	
1N1189	1N1189A	1N2137A	500 (1)	500 (1)	
1N1190	1N1190A	1N2138A	600 ⁽¹⁾	600 ⁽¹⁾	
1N3765			700 (1)	700 (1)	
1N3766			800 (1)	800 (1)	
1N3767			900 (1)	900 (1)	
1N3768			1000 (1)	1000 (1)	

Notes

⁽¹⁾ JEDEC registered values

 $^{(2)}$ For 1N1183 Series and 1N3765 Series T_C = - 65 $^\circ C$ to 190 $^\circ C$

• Basic type number indicates cathode to case. For anode to case, add "R" to part number, e.g., 1N1188R, 1N3766R, 1N1186AR, 1N2135AR



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FORWARD CONDUCTION								
PARAMETER	SYMBOL	TEST CONDITIONS		1N1183	1N3765	1N1183A	1N2128A	UNITS
Maximum average forward current		1-phase operation,		35 ⁽¹⁾	35 ⁽¹⁾	40 ⁽¹⁾	60 ⁽¹⁾	A
at case temperature		180° sinusoidal conduction		140 ⁽¹⁾	140 (1)	150 ⁽¹⁾	140 ⁽¹⁾	°C
		rectangular pulse	Following any rated load condition and	480	380	765	860	0 ⁽¹⁾ A
Maximum peak one cycle		Half cycle 60 Hz sine wave or 5 ms rectangular pulse	with rated V _{RRM} applied	500 ⁽¹⁾	400 (1)	800 (1)	900 (1)	
non-repetitive surge current	IFSM	Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and	570	455	910	1000	
		Half cycle 60 Hz sine wave or 5 ms rectangular pulse	with ½ V _{RRM} applied following surge = 0	595	475	950	1050	
Maximum I ² t for fusing		t = 10 ms	With rated V_{RRM} applied following surge, initial $T_J = T_J$ maximum With $V_{RRM} = 0$ following surge, initial $T_J =$ T_J maximum	1140	730	2900	3700	A ² s
Maximum int for fusing	124	t = 8.3 ms		1040	670	2650	3400	
Maximum I ² t for individual	l ² t	t = 10 ms		1610	1030	4150	5250	
device fusing		t = 8.3 ms		1470	940	3750	4750	
Maximum I²√t for individual device fusing	²√t (2)	t = 0.1 to 10 ms, V _{RRM} = 0 following surge		16 100	10 300	41 500	52 500	A²√s
Maximum peak forward voltage	V	$T_{\rm J} = 25 \ ^{\circ}{\rm C} \qquad \qquad \frac{1.7 \ ^{(1)}}{110} \qquad \frac{1.8 \ ^{(1)}}{110}$		1.7 ⁽¹⁾	1.8 ⁽¹⁾	1.3 ⁽¹⁾	1.3 ⁽¹⁾	V
at maximum forward current (I $_{\mbox{FM}}$)	V _{FM}			126	188	А		
V _{RRM} = 700	1	Maximum rated $I_{F(AV)}$ and T_{C}		-	5.0 ⁽¹⁾	-	-	
V _{RRM} = 800				-	4.0 (1)	-	-	
Maximum average reverse current	I _{R(AV)}	waximum rated I _{F()}	v) and i c	-	3.0 ⁽¹⁾	-	-	mA
$V_{\text{RRM}} = 1000$				-	2.0 (1)	-	-	
		Maximum rated $I_{F(AV)}$, V_{RRM} and T_{C}		10 ⁽¹⁾	-	2.5 ⁽¹⁾	10 ⁽¹⁾	

Notes

(1) JEDEC registered values

(2) I²t for time $t_x = I^2 \sqrt{t} x \sqrt{t_x}$



Power Silicon Rectifier Diodes, Vishay High Power Products 35 A/40 A/60 A

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	1N1183	1N3765	1N1183A	1N2128A	UNITS
Maximum operating T _C			- 65 to 190 ⁽¹⁾ - 65 to 200		°C		
Maximum storage temperature range	T _{Stg}		- 65 to	- 65 to 175 ⁽¹⁾ - 65 to 2		o 200	
Maximum internal thermal resistance, junction to case	R _{thJC}	DC operation	1.00 ⁽¹⁾		1.1 ⁽¹⁾	0.65 ⁽¹⁾	°C/W
Thermal resistance, case to sink	But Report Mounting surface, smooth, flat and greased 0.25				0/11		
		Not lubricated thread, tighting on nut ⁽²⁾	3.4 (30)			N·m	
Maximum allowable		Lubricated thread, tighting on nut ⁽²⁾	2.3 (20) 4.2 (37)				
mounting torque (+ 0 %, - 10 %)		Not lubricated thread, tighting on hexagon (3)				(lbf · in)	
		Lubricated thread, tighting on hexagon (3)	3.2 (28)				
Approvimato woight			17			g	
Approximate weight					0.6		OZ.
Case style		JEDEC		DC	-203AB (D	D- 5)	•

Notes

(1) JEDEC registered values

(2) Recommended for pass-through holes
(3) Recommended for holed threaded heatsinks

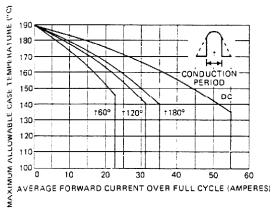


Fig. 1 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N1183 and 1N3765 Series

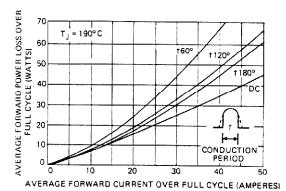


Fig. 2 - Typical Low Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform),

1N1183 and 1N3765 Series

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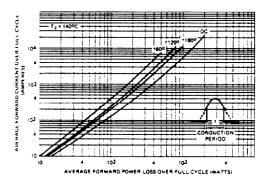


Fig. 3 - Typical High Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform), 1N1183 and 1N3765 Series

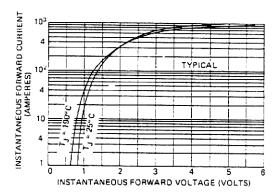
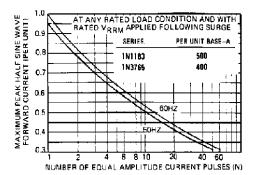
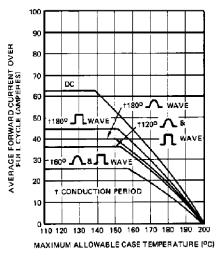
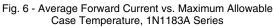


Fig. 4 - Typical Forward Voltage vs. Forward Current, 1N1183 and 1N3765 Series









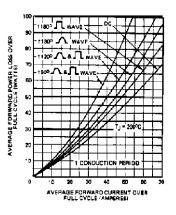


Fig. 7 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N1183A Series

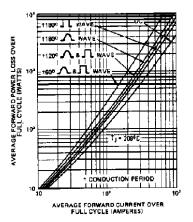


Fig. 8 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N1183A Series



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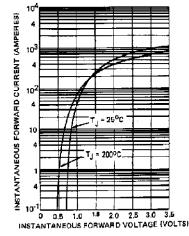


Fig. 9 - Maximum Forward Voltage vs. Forward Current, 1N1183A Series

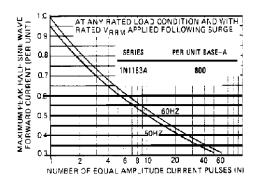
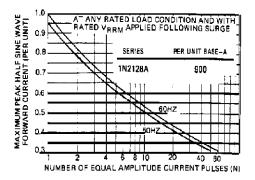
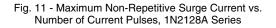


Fig. 10 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183A Series





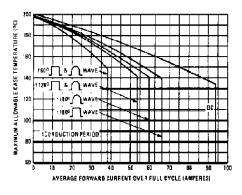


Fig. 12 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N2128A Series

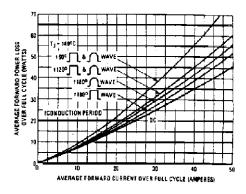


Fig. 13 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N2128A Series

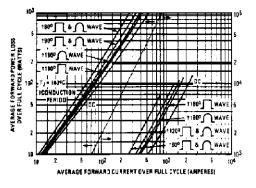
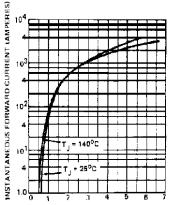


Fig. 14 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N2128A Series

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INSTANTANEOUS FORWARD VOLTAGE (VOLTS)

Fig. 15 - Maximum Forward Voltage vs. Forward Current, 1N2128A Series

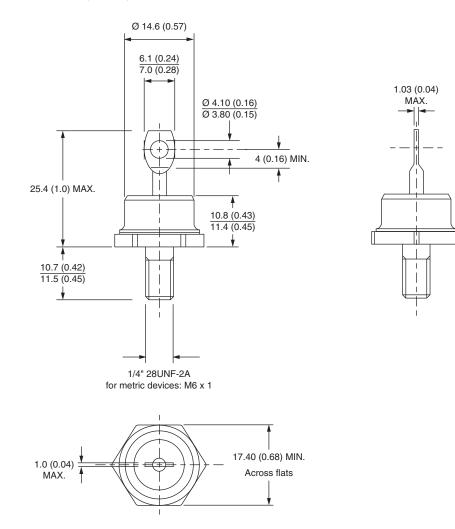
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95360			

Vishay Semiconductors

DO-203AB (DO-5) for 1N1183, 1N3765, 1N1183A, 1N2128A, 1N3208 Series

DIMENSIONS in millimeters (inches)

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